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Electronic properties of Li-doped zigzag graphene nanoribbons

P. Narin^{a,*}, E. Kutlu^a, B. Sarikavak-Lisesivdin^a, S.B. Lisesivdin^a, E. Özbay^{b,c,d}

^a Department of Physics, Faculty of Science, Gazi University, Teknikokullar, 06500 Ankara, Turkey

^b Nanotechnology Research Center, Bilkent University, Bilkent, 06800 Ankara, Turkey

^c Department of Physics, Bilkent University, Bilkent, 06800 Ankara, Turkey

^d Department of Electrical and Electronics Engineering, Bilkent University, Bilkent, 06800 Ankara, Turkey

HIGHLIGHTS

• Electronic properties of Li-doped ZGNR are investigated.

• Spin polarized calculations are carried out with DFT.

• ZGNR is exhibited half metallic or semiconductor behavior.

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1. Introduction

Since the discovery of graphene, intensive works have been carried out on this material [1-4]. Carbon nano-materials have become the focus of attention for the last 20 years because low dimensional characteristics and unique electronic properties [5,6]. Graphene nanoribbons (GNRs) exhibit quite significant features indicating that they will have high usage possibility for carbonbased nano-electronics [7-10]. GNRs have a one-dimensional structure. Their structural and electronic characteristics have been examined in detail in both experimental and theoretical studies [11]. GNR structures are of two types including Zigzag edged (ZGNR) and Armchair (AGNR) edged types [12]. AGNR structures are exhibiting metallic or semiconducting behaviors for their different widths [13–15]. ZGNRs are mostly behaving metallic. However, ZGNRs show edge-related magnetism [7,15,16]. Therefore, behavior of the band structure is much more complex than the AGNRs. According to some theoretical works, an applied

* Corresponding author. E-mail address: polatnarin0@gmail.com (P. Narin).

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ABSTRACT

Zigzag graphene nanoribbons (ZGNRs) are known to exhibit metallic behavior. Depending on structural properties such as edge status, doping and width of nanoribbons, the electronic properties of these structures may vary. In this study, changes in electronic properties of crystal by doping Lithium (Li) atom to ZGNR structure are analyzed. In spin polarized calculations are made using Density Functional Theory (DFT) with generalized gradient approximation (GGA) as exchange correlation. As a result of calculations, it has been determined that Li atom affects electronic properties of ZGNR structure significantly. It is observed that ZGNR structure exhibiting metallic behavior in pure state shows half-metal and semiconductor behavior with Li atom.

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electric field perpendicular to the nanoribbon itself, may change the behavior of the ribbon between a semiconducting and a halfmetallic state due to effect of the electric field on an antiferromagnetic edge state [9,17].

GNR structures show opposite behavior exhibit metallic behavior compared to carbon nanotubes in terms of their electronic properties [18-20]. However, some theoretical studies may show different electronic properties of carbon nanotubes [14,20,21].

Electronic properties of GNR structures can be explained with both their edge states and nanoribbon width and are known to change with doping [22–25]. Because of having spintronic features, electronic properties of GNR structures can be analyzed based on spin [26,27]. Apart from metallic and semiconducting states, electronic band structure depending on different spin states, it is known that there are concepts such as half-metal and spin-gapless semiconductor [28]. Generally, the structure with one spin state with metallic behavior and other spin state with semiconductor behavior is called half metallic. If parallel spin or opposite spin bands touch each other at the Fermi point, this is called the spin-gapless semiconductor state [28]. And, half metal cases is usually observed in zigzag edged GNRs. Three properties can bring ZGNR structure to half metal state; changing of edges of ZGNR,





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doping with atoms or applying of an external electric field [7,23,29–31].

Li atom substantially is used making energy storage and conversion such as lithium ion batteries (LIBs), supercapacitors and fuel cells in graphene-based nanomaterials [32,33]. Besides energy storage and conversion, LIBs have become important for movable electronic devices because of their rechargeable properties in last two decades [32]. Therefore other than graphene, using Li atoms with other carbon-based materials may affect the electronic properties of those materials significantly. Previously, Li atom was used as adatom in zigzag graphene nanoribbon [34–38]. To our knowledge, the electronic properties of substitutional Li doped GNRs were not studied yet.

In this study, the effect of doping of Li atom on electronic properties of ZGNR structures were analyzed theoretically with the help of motivation given by the possible important applications of Li interacted graphene-based nanomaterials.

2. Calculation method

Calculations were carried out using Atomistix Toolkit–Visual NanoLab (ATK-VNL) software based on the DFT calculations [39,40]. In spin polarized calculations have been carried out with generalized gradient approximation (GGA) and Perdew–Burke–Ernzerhof (PBE) was used as exchange correlation functional [41]. In calculations, nano-ribbons terminated with hydrogen atoms with width (N_z) between 4 and 12 has been used. However, since the results of the structures with different N_z gave similar results, only results from the state where $N_z=8$ have been evaluated throughout the article. In calculations for the studied structures; cut-off energy and maximum force applied to the crystal are taken respectively as 300 eV and 0.05 eV/Å. In addition, the periodic boundary condition was accepted along *z*-axis and Monkhorst–Pack $1 \times 1 \times 100$ k-point grid parameters have been used.

$$E_B = E_T - E_{T:bare} - nE_H - mE_{Li} \tag{1}$$

$$E_{\rm F} = (E_{T:dop} + E_c) - (E_{T:H} + mE_{Li})$$
(2)

Solving Eq. (1) and Eq. (2), it has been determined on which doping sites at 8-ZGNR structure is steady [49]. In Eq. (1), E_B is binding energy, E_T is the doped structure's total energy, $E_{T:bare}$ is total energy of ZGNR without finishing with any atoms, E_H and E_{Li} are free energy of a half of a isolated H₂ molecule and a lithium atom, *n* and *m* are the number of H atoms and Li atom in the structure. In Eq. (2), E_F is the formation energy, $E_{T:dop}$ is total energy of doped structure, E_c is free energy of a carbon atom, $E_{T:H}$ is the total energy of the structure terminated with hydrogen.

3. Results and discussion

8-ZGNR structure used in calculations is represented in Fig. 1. In the cell, positions of possible Li doping sites are assigned with a letter from A to G, and for each site, electronic band structure and density of states (DOS) have been examined. As a result of Eqs. (1) and (2), formation energy and binding energy values given with in Fig. 2 have been determined. While low binding and low formation energies are observed in Li doping sites with even numbered lines as shown in Fig. 2, high binding and formation energies are observed in odd numbered lines.

In literature, it is known that Li atom to hollow site of graphene is more stable than that of bridge and top sites [43,44]. Binding and formation energies of Li atom doped to hollow site of graphene have been shown in Table 1. As shown, binding and



Fig. 1. Schematic view of Li dosing in different positions of nanoribbon, naming from letter A to G corresponds to doping positions in 8-ZGNR.



Fig. 2. Binding and formation energy changes depending on the position of Li atom within 8-ZGNR.

Table 1

For Li-doped structures, binding and formation energies of this and previously studies.

	Binding energy (eV)	Formation energy (eV)
Graphene (hollow site)		
	1.60 [42]	7.83 [46]
	1.55 [43]	7.2–7.9 [47]
	1.93 [45]	
This study	2.21	15.99

formation energies of Li doped graphene are lower than our results. However, binding energy of this study is stronger than that of graphene. This binding energy is consistent with previous study which is binding energy of Li adsorption on ZGNR [48].

In Fig. 3, electronic band structure and DOS of 8-ZGNR

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